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SINGLE 2 INPUT POSITIVE OR GATE

Description

The 74LVCE1G32 is a single 2-input positive OR gate with a standard totem pole output. The device is designed for operation with a power supply range of 1.4V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

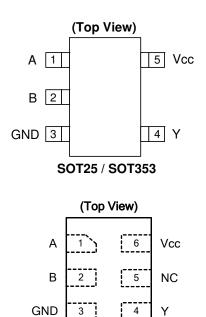
The gate performs the positive Boolean function:

$$Y = A + B$$
 or $Y = \overline{\overline{A \bullet B}}$

Features

- Extended Supply Voltage Range from 1.4 to 5.5V
- Switching speed characterized for operation at 1.5V
- Offers 30% speed improvement over LVC at 1.8V.
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 200-V Machine Model (A115-A)
 Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- · Direct Interface with TTL Levels
- SOT25, SOT353, and DFN1410: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Pin Assignments



DFN1410 (Note 2)

Applications

- Voltage Level Shifting
- Bus Driver / Repeater
- Power Down Signal Isolation
- General Purpose Logic
- Wide array of products such as.
 - o PCs, networking, notebooks, netbooks, PDAs
 - o Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - o Cell Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

2. Pin 2 and pin 5 of the DFN1410 package are internally connected.

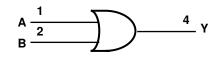


SINGLE 2 INPUT POSITIVE OR GATE

Pin Descriptions

Pin Name	Description
А	Data Input
В	Data Input
GND	Ground
Y	Data Output
Vcc	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
Α	В	Y
Н	Х	Н
Х	Н	Н
L	L	L



SINGLE 2 INPUT POSITIVE OR GATE

Absolute Maximum Ratings (Note 3)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
V	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or IOFF state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
Ι _{ΟΚ}	Output Clamp Current	-50	mA
Ι _Ο	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Note: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



SINGLE 2 INPUT POSITIVE OR GATE

Recommended Operating Conditions (Note 4)

Symbol		Parameter	Min	Max	Unit	
M		Operating	1.4	5.5	V	
V_{CC}	Operating Voltage	Data retention only	1.2		V	
		V _{CC} = 1.4 V to 1.95 V	0.65 X V _{CC}			
N/		$V_{\rm CC}$ = 2.3 V to 2.7 V	1.7		V	
V _{IH} Hiệ	High-level Input Voltage	V _{CC} = 3 V to 3.6 V	2		V	
		$V_{\rm CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	0.7 X V _{CC}			
		V _{CC} = 1.4 V to 1.95 V		0.35 X V_{CC}		
N/	V _{IL} Low-level input voltage	$V_{\rm CC} = 2.3 \text{ V}$ to 2.7 V		0.7	V	
VIL		V _{CC} = 3 V to 3.6 V		0.8	V	
		$V_{\rm CC} = 4.5 \text{ V}$ to 5.5 V		0.3 X V _{CC}		
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage		0	V _{CC}	V	
	High-level output current	Vcc=1.4 V		-3		
		V _{CC} = 1.65 V		-4		
		V _{CC} = 2.3 V		-8		
I _{OH}				-16	mA	
		$V_{CC} = 3 V$		-24		
		$V_{\rm CC} = 4.5 \text{ V}$		-32		
		Vcc=1.4 V		3		
		V _{CC} = 1.65 V		4		
		$V_{\rm CC} = 2.3 \rm V$		8	mA	
I _{OL}	Low-level output current			16		
		$V_{CC} = 3 V$		24		
		$V_{\rm CC} = 4.5 \rm V$		32		
		$V_{CC} = 1.4$ to 3V		20		
Δt/ΔV	Input transition rise or fall	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
	rate	$V_{CC} = 5 V \pm 0.5 V$		5		
T _A	Operating free-air temperature		-40	85	°C	

Note: 4. Unused inputs should be held at Vcc or Ground.



SINGLE 2 INPUT POSITIVE OR GATE

Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25°C)

Symbol	Parameter	Test Conditions	Vcc	Min	Тур.	Max	Unit	
		I _{OH} = -100μA	1.4 V to 5.5V	$V_{CC} - 0.1$				
		I _{OH} = -3mA	1.4 V	1.05				
		I _{OH} = -4mA	1.65 V	1.2				
V _{OH}	High Level Output Voltage	I _{OH} = -8mA	2.3V	1.9			V	
	Voltage	I _{OH} = -16mA	3 V	2.4				
		I _{OH} = -24mA	- 3 V	2.3				
		I _{OH} = -32mA	4.5 V	3.8				
		I _{OL} = 100μA	1.4 V to 5.5V			0.1		
		I _{OL} = 3mA	1.4 V			.4		
V _{OL}		$I_{OL} = 4mA$	1.65 V			0.45	V	
	High-level Input Voltage	I _{OL} = 8mA	2.3V			0.3		
		I _{OL} = 16mA	3 V			0.4		
		$I_{OL} = 24mA$	5 V			0.55		
		I _{OL} = 32mA	4.5			0.55		
I _I	Input Current	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5 V			± 5	μA	
I _{OFF}	Power Down Leakage Current	$V_1 \text{ or } V_0 = 5.5 V$	0			± 10	μA	
I _{CC}	Supply Current	$V_1 = 5.5V \text{ of } GND$ $I_0=0$	1.4 V to 5.5V			10	μA	
ΔI _{CC}	Additional Supply Current	One input at V_{CC} – 0.6 V Other inputs at V_{CC} or GND	3 V to 5.5V			500	μA	
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	3.3		3.5		pF	
		SOT25	(Note 5)		204			
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT353	(Note 5)		371		°C/W	
		DFN1410	(Note 5)		430]	
		SOT25	(Note 5)		52			
$\theta_{\rm JC}$	Thermal Resistance Junction-to-Case	SOT353	(Note 5)		143		°C/W	
	Junction-to-Case	DFN1410	(Note 5)		190			

Note: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



SINGLE 2 INPUT POSITIVE OR GATE

Switching Characteristics

Parameter From		то	Vcc = ± 0			: 1.8 V .15V		: 2.5 V).2V		3.3 V .3V	Vcc ± 0	= 5 V).5V	Unit
T urumeter	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Мах	Min	Max	•
t _{pd}	A or B	Y	1.9	7.2	1.3	5	0.6	3.5	0.7	2.9	0.7	2.9	ns

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

Parameter	From TO		Vcc = ± 0			: 1.8 V .15V		: 2.5 V).2V		: 3.3 V).3V	Vcc ±0	= 5 V).5V	Unit
T urumeter	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Мах	•
t _{pd}	A or B	Y	2.8	8	1.9	5.6	0.9	4.4	0.9	3.6	0.9	3.6	ns

Operating Characteristics

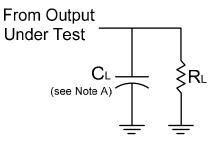
 $T_A = 25 \ ^{o}C$

Р	arameter		Vcc = 1.5 V	Vcc = 1.8 V	Vcc = 2.5 V	Vcc = 3.3 V	Vcc = 5 V	Unit
		Conditions	ТҮР	ТҮР	ТҮР	ТҮР	ТҮР	
C_{pd}	Power dissipation capacitance	f = 10 MHz	20	20	20	21	22	pF

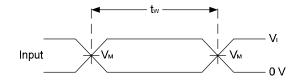


SINGLE 2 INPUT POSITIVE OR GATE

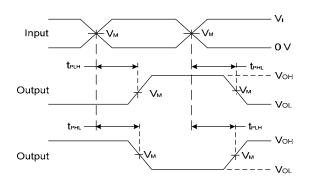
Parameter Measurement Information



Vcc		outs	V _M	CL	RL	
VCC	VI	t _r /t _f	¥М	υL	ΠL	
1.5V±0.1V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ	
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ	
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ	
3.3V±0.3V	ЗV	≤2.5ns	1.5V	15pF	1MΩ	
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	15pF	1MΩ	



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate \leq 10 MHz. C. Inputs are measured separately one transition per measurement.

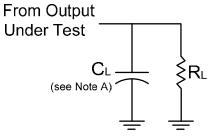
D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$

Figure 1. Load Circuit and Voltage Waveforms

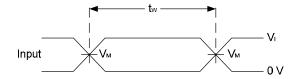


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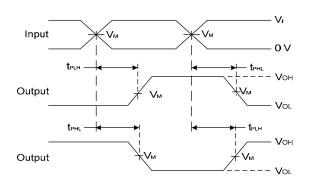
Parameter Measurement Information (Continued)



Vcc	Ing	outs	V _M	CL	RL	
	VI	t _r /t _f	- 101	<u> </u>		
1.5V±0.1V	V _{CC}	≤2ns	V _{CC} /2	30pF	1KΩ	
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	30pF	1KΩ	
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	30pF	500Ω	
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω	
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	50pF	500Ω	



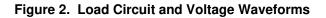
Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

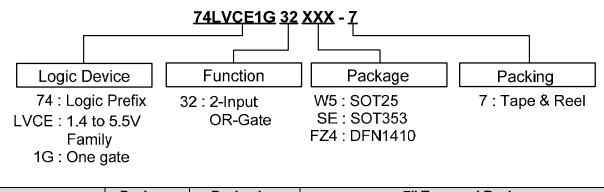
- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$





SINGLE 2 INPUT POSITIVE OR GATE

Ordering Information



	Device	Package	Packaging	7" Tape a	and Reel		
	Device	Code	(Note 5)	Quantity	Part Number Suffix		
Pb ,	74LVCE1G32W5-7	W6	SOT25	3000/Tape & Reel	-7		
Pb ,	74LVCE1G32SE-7	SE	SOT353	3000/Tape & Reel	-7		
Pb	74LVCE1G32FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7		

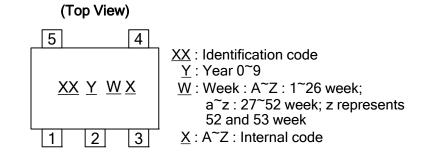
Note: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



SINGLE 2 INPUT POSITIVE OR GATE

Marking Information

(1) SOT25 and SOT353



	Part Number	Package	Identification Code
ĺ	74LVCE1G32W5	SOT25	PW
	74LVCE1G32SE	SOT353	PW

(2) DFN1410

(Top View)



- XX : Identification Code
- <u>Y</u> : Year : 0~9
- <u>W</u>: Week : A~Z : 1~26 week; a~z : 27~52 week; z represents 52 and 53 week
- \underline{X} : A~Z : Internal code

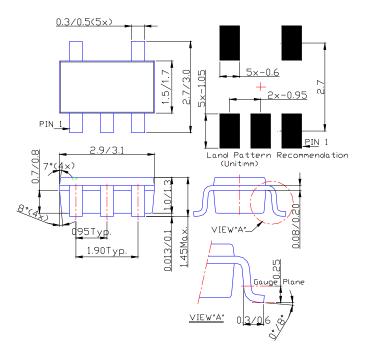
Part Number	Package	Identification Code
74LVCE1G32FZ4	DFN1410	PW



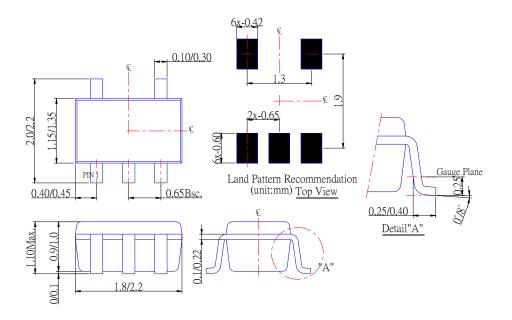
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Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



(2) Package Type: SOT353



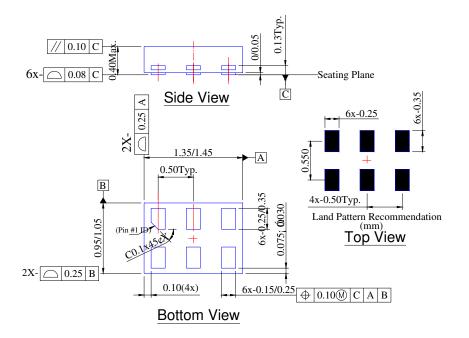
74LVCE1G32 Document number: DS32214 Rev. 2 - 2



SINGLE 2 INPUT POSITIVE OR GATE

Package Outline Dimensions (All Dimensions in mm)

(3) Package Type: DFN1410

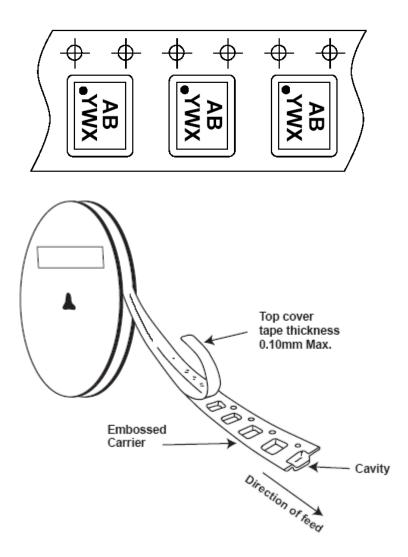


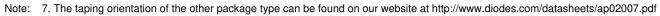


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Taping Orientation (Note 7)

For DFN1410







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